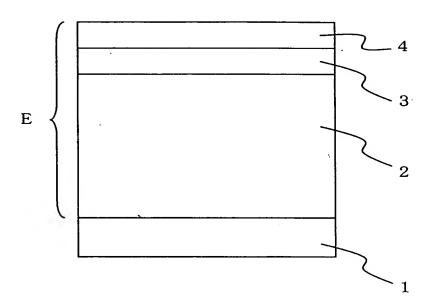
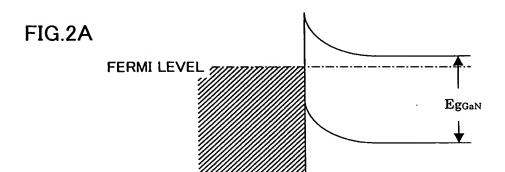
App No.: Not Yet Assigned Docket No.: 24540200
Inventor: Nobuaki TERAGUCHI
Title: ELECTRODE EMPLOYING NITRIDE-BASED
SEMICONDUCTOR OF III-V GROUP COMPOUND, AND
PRODUCING METHOD THEREOF Docket No.: 245402008300

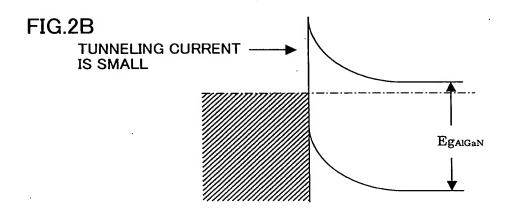
FIG.1



Docket No.: 245402008300

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Inventor: Nobuaki TERAGUCHI
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PRODUCING METHOD THEREOF





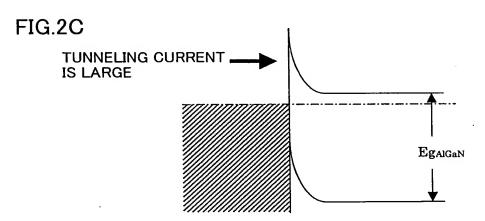
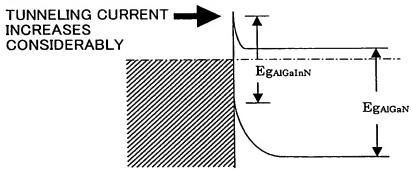


FIG.2D



Docket No.: 245402008300 App No.: Not Yet Assigned Inventor: Nobuaki TERAGUCHI Title: ELECTRODE EMPLOYING NITRIDE-BASED

SEMICONDUCTOR OF III-V GROUP COMPOUND, AND

PRODUCING METHOD THEREOF

FIG.3

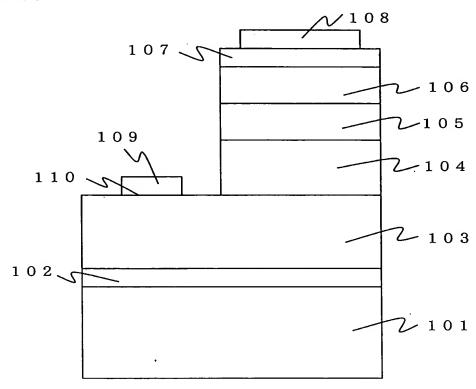
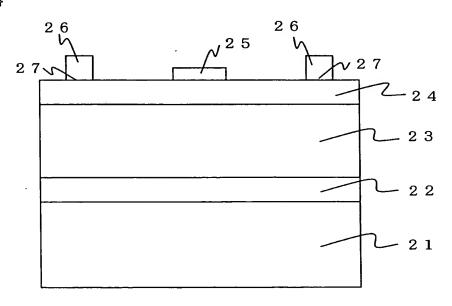


FIG.4



App No.: Not Yet Assigned Docket No.: 245402008300 Inventor: Nobuaki TERAGUCHI

Title: ELECTRODE EMPLOYING NITRIDE-BASED SEMICONDUCTOR OF III-V GROUP COMPOUND, AND

PRODUCING METHOD THEREOF

FIG.5

